

# Tunnelling spectroscopy of the interface between $\text{Sr}_2\text{RuO}_4$ and a single Ru micro-inclusion in eutectic crystals

Hiroshi Yaguchi<sup>1</sup>, Keiichi Takizawa<sup>1</sup>, Minoru Kawamura<sup>2,3</sup>, Naoki Ikigawa<sup>1</sup>, Yoshitenu Maeno<sup>1,4</sup>, Takayoshi Mieno<sup>5</sup>, Tatsushi Akazaki<sup>2</sup>, Kouichi Semba<sup>2</sup> and Hideaki Takayanagi<sup>2</sup>

<sup>1</sup>Department of Physics, Graduate School of Science, Kyoto University, Kyoto 606-8502

<sup>2</sup>NTT Basic Research Laboratories, NTT Corporation, Atsugi, Kanagawa 243-0198

<sup>3</sup>RIKEN, Wako, Saitama 351-0198

<sup>4</sup>Kyoto University International Innovation Center, Kyoto 606-8501

<sup>5</sup>NTT-ATN Corporation, Atsugi, Kanagawa 243-0018

**KEYWORDS:**  $\text{Sr}_2\text{RuO}_4$ , tunnelling spectroscopy, zero bias conductance peak, spin-triplet superconductivity, ruthenate

The understanding of the zero bias conductance peak (ZBCP) in the tunnelling spectra of S/N junctions involving d-wave cuprate superconductors has been important in the determination of the phase structure of the superconducting order parameter.<sup>1</sup> In this context, the involvement of a p-wave superconductor such as  $\text{Sr}_2\text{RuO}_4$  in tunnelling studies is indeed of great importance. We have recently succeeded in fabricating devices that enable S/N junctions forming at interfaces between  $\text{Sr}_2\text{RuO}_4$  and Ru micro-inclusions in eutectic crystals to be investigated.<sup>3</sup> We have observed a ZBCP and have interpreted it as due to the Andreev bound state, commonly seen in unconventional superconductors. Also we have proposed that the onset of the ZBCP may be used to delineate the phase boundary for the onset of a time reversal symmetry broken (TRSB) state within the superconducting state, which does not always coincide with the onset of the superconducting state.<sup>3</sup> However, these measurements always involved two interfaces between  $\text{Sr}_2\text{RuO}_4$  and Ru. In the present study, we have extended the previous measurements to obtain a deeper insight into the properties of a single interface between  $\text{Sr}_2\text{RuO}_4$  and Ru.

The layered perovskite  $\text{Sr}_2\text{RuO}_4$ , recognised as one of the strongest candidates for a spin-triplet superconductor, has attracted great research interest in spite of its relatively low  $T_c$  of 1.5 K.<sup>4</sup> Taken together several experiments, such as NMR<sup>5</sup> and muon spin relaxation,<sup>6</sup> the basic form of the vector order parameter is constrained to be  $d(k) = z_0(k_x + ik_y)$ , corresponding to a TRSB state (the chiral state). Although this basic form is too simplified to explain other existing experimental results, the incorporation of band-dependent gap structure and strong in-plane anisotropy of the superconducting gap allows the existing experimental results to be reconciled.<sup>7</sup>

Interesting aspects of  $\text{Sr}_2\text{RuO}_4$  include superconductivity in eutectic systems such as  $\text{Sr}_2\text{RuO}_4\text{-Ru}$ <sup>8</sup> and  $\text{Sr}_2\text{RuO}_4\text{-Sr}_3\text{Ru}_2\text{O}_7$ .<sup>9</sup> In  $\text{Sr}_2\text{RuO}_4\text{-Ru}$ , superconductivity with an enhanced  $T_c$ , called the 3-K phase, is known

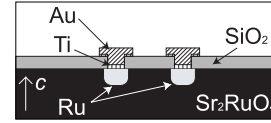


Fig. 1. Cross-sectional schematic of S/N junctions of  $\text{Sr}_2\text{RuO}_4$  and Ru with Ti/Au electrodes attached on the Ru inclusions. Measurement current flows between the two electrodes through the two S/N junctions.

to occur within  $\text{Sr}_2\text{RuO}_4$  at interfaces between  $\text{Sr}_2\text{RuO}_4$  and Ru micro-inclusions. Besides this, these eutectic systems, as a consequence of the eutectic solidification, contain natural interfaces with the spin-triplet superconductor  $\text{Sr}_2\text{RuO}_4$ . Under certain circumstances, such interfaces may be regarded as superconductor/normal metal (S/N) junctions. In fact, Mao et al. performed break-junction experiments on  $\text{Sr}_2\text{RuO}_4\text{-Ru}$  eutectic and observed a ZBCP characteristic of unconventional superconductivity.<sup>10</sup>

Recently, as mentioned earlier, we have also used interfaces in eutectic  $\text{Sr}_2\text{RuO}_4\text{-Ru}$  to obtain well-defined S/N junctions illustrated in Fig. 1, using a micro-fabrication technique. Details of the fabrication and the crystal growth are described in Refs. 3 and 8. As depicted in Fig. 1, each S/N junction possesses a Ti/Au electrode directly attached to the Ru micro-inclusion through 2  $\mu\text{m}$   $\times$  3  $\mu\text{m}$  rectangular contact windows. The  $\text{SiO}_2$  film is an insulating layer deposited on the ab-plane of  $\text{Sr}_2\text{RuO}_4$ . Achieving good electrical contacts is possible practically only on Ru inclusions because of a non-superconducting layer with a high resistivity forming on the ab-plane surface of  $\text{Sr}_2\text{RuO}_4$ . Consequently, actual measurement current is injected via two electrodes on Ru inclusions. Therefore, the two  $\text{Sr}_2\text{RuO}_4\text{/Ru}$  junctions in series are inevitably involved for the measurement. Besides, this measurement configuration leads to the resistances of the S/N junctions,  $\text{Sr}_2\text{RuO}_4$ , Ru and Ti/Au electrodes in series all contributing to the whole resistance measured. However, the resistance measured is dominated by that of the  $\text{Sr}_2\text{RuO}_4\text{/Ru}$  junctions because the resistance measured, typically on the order of 1  $\Omega$ , is much larger than the resistance of the other components. We use the identical devices also in the present study. A lock-in technique was employed to measure the differential conductance.

Similarly to work in Ref. 10, we observed a clear ZBCP in the previous study in Ref. 3. The ZBCP is attributed to a sign change in the order parameter on the Fermi surface, characteristic of unconventional superconductivity. Figure 2 shows two spectra of different devices at 0.6 K. The upper trace was obtained using the same device as used in the previous study,<sup>3</sup> and shows a sharp ZBCP in addition to a broad peak. By contrast, the lower trace appears to be similar but without a sharp ZBCP. Such S/N junctions may be phenomenologically modelled using a steep barrier at the interface, assuming a  $\delta$ -function potential with its strength  $Z$ . With increasing  $Z$ , the tunnelling limit, where the resultant spectra represent the density of states at the interface, is approached.<sup>11</sup> In this context, the overall similarity of the two spectra and

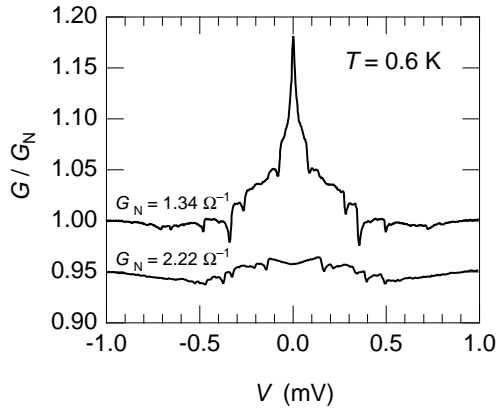


Fig. 2. Normalised differential conductances of two devices at  $T = 0.6$  K and  $H = 0$  as a function of the bias voltage. The upper trace shows a zero bias conductance peak whilst the other does not. Traces have been offset for clarity.

the moderate closeness of the normal conductance values may suggest the proximity of interface conditions such as the barrier height (probably rather high  $Z$ ), whereas the origin of their difference is unclear. Based on this assumption, these observations perhaps signal that the spectrum depends on the (effective) direction of the interface relative to the crystallographic axes. In fact, S/N junctions including high  $T_c$  cuprates with d-wave pairing show strong dependence of the tunnelling spectrum on the direction of the interface. It is well established that the height of ZBCP takes a maximum (minimum) for  $\theta = \pi/8$  ( $\theta = 0$ ), where  $\theta$  is the angle between the normal to the interface and the direction of a lobe of the d-wave order parameter.<sup>1,12</sup> This was first theoretically suggested<sup>1</sup> and later demonstrated by well-controlled experiments.<sup>12</sup> It should be noted that the phase associated with the chiral state changes continuously between 0 and  $2\pi$ , while the phase of the superconducting order parameter of high  $T_c$  cuprates takes either 0 or  $\pi$ .

Although the basic form of the superconducting order parameter for  $\text{Sr}_2\text{RuO}_4$  is  $d = z(k_x + ik_y)$  and isotropic, the gap function is considerably anisotropic in reality. A realistic gap function (on the band) is considered to be  $d = z[\sin(k_x) + i\sin(k_y)]$ ,<sup>7</sup> possessing strong in-plane anisotropy. In fact, the isotropic gap associated with  $d = z(k_x + ik_y)$  leads to a broad ZBCP,<sup>13</sup> so that the observed sharp ZBCP has not been well explained. Further theoretical studies are awaited to understand the detailed spectra with more realistic band and superconducting gap structures incorporated.

Finally, we discuss the width of the superconducting gap observed. The study in Ref. 10 and our previous and present studies employ eutectic  $\text{Sr}_2\text{RuO}_4$ -Ru and thus involve 3-K phase superconductivity,<sup>8</sup> which occurs on the  $\text{Sr}_2\text{RuO}_4$  side of the interface. While the spectra obtained in our present and previous studies are very similar to those previously reported on experiments using a break junction technique in Ref. 10, the width of the whole conductance peak in the present study is considerably smaller than that reported.<sup>10</sup> We suggest that this quantitative difference between those works may be

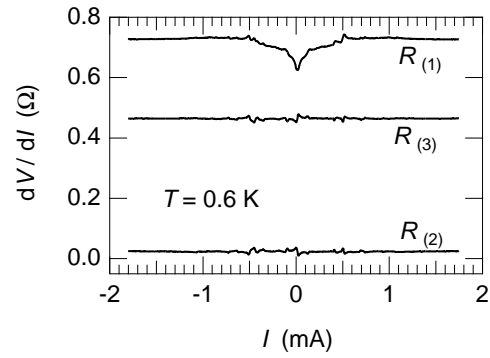


Fig. 3. Decomposed spectra as a function of current. Only one of the three interfaces is responsible for the clear ZBCP observed while the other junctions hardly show such a peaked feature. (For details, see text.)

attributed to the difference in the number of junctions involved effectively. While our measurements inevitably involve two junctions in series from the geometrical configuration, the work in Ref. 10 may involve several interfaces in parallel and/or series.

We have confirmed that only one of the two junctions, i.e. a single interface of  $\text{Sr}_2\text{RuO}_4$  and Ru, is responsible for the ZBCP shown in Fig. 2 in the following way. We made three sets of measurements with a third junction involved and obtained the (differential) resistance between two junctions  $R_{ij}$ . We here label the resistance between the  $i$ -th and  $j$ -th junctions  $R_{ij}$  and the resistance of the  $i$ -th junction  $R_{(i)}$ . (The upper trace in Fig. 2 corresponds to  $R_{12}$ .) As mentioned earlier, the resistance measured is dominated by the resistance of the  $\text{Sr}_2\text{RuO}_4$ /Ru junctions. Consequently, the use of the assumption  $R_{ij} = R_{(i)} + R_{(j)}$  etc. is reasonable, and allows the resistances between junctions to be decomposed into the resistance of each junction  $R_{(i)}$ . e.g.  $R_{(1)} = (R_{12} + R_{23} + R_{31})/2 = R_{23}$ . Figures 2 and 3 show the resultant resistance of each junction. Only one of the three junctions is responsible for the observed ZBCP.<sup>14</sup> Based on  $R_{(1)}$  in Fig. 3, the simple attribution of the width of the broad peak to the gap width yields  $2\Delta = 0.7$  meV (at 0.6 K), corresponding to  $2\Delta = k_B T_c$  (3 ( $T_c = 2.7$  K)). (The spectrum is fairly flat in the range  $|I| > 0.35$  mA, in support of the above attribution  $2\Delta = 0.7$  meV.) The broad peak persists well above  $T_c$  of  $\text{Sr}_2\text{RuO}_4$ , indicative of the gap being associated with the 3-K phase<sup>3,10,15</sup>.

#### Acknowledgment

This work was supported in part by Grants-in-Aid for Scientific Research from the JSPS and 21COE program on Center for Diversity and Universality in Physics from the MEXT of Japan.

- 1) Y. Tanaka and S. Kashiwaya: Phys. Rev. Lett. 74 (1995) 3451.
- 2) Y. M. Aeno, H. Hashimoto, K. Yoshida, S. Nishizaki, T. Fujita, J. G. Bednorz and F. Lichtenberg: Nature 372 (1994) 532.
- 3) M. Kawamura, H. Yaguchi, N. Kikugawa, Y. M. Aeno and H. Takayanagi: J. Phys. Soc. Jpn. 74 (2005) 531.

- 4) A. P. Mackenzie and Y. Maeno: Rev. Mod. Phys. 75 (2003) 657.
- 5) K. Ishida, H. Mukuda, Y. Kitaoka, K. Asayama, Z. Q. Mao, Y. Mori and Y. Maeno: Nature 396 (1998) 658.
- 6) G. M. Luke, Y. Fudamoto, K. M. Kojima, M. I. Larkin, J. Merrin, B. Nachumi, Y. J. Uemura, Y. Maeno, Z. Q. Mao, Y. Mori, H. Nakamura, and M. Sigrist: Nature 394 (1998) 558.
- 7) K. Deguchi, Z. Q. Mao and Y. Maeno: J. Phys. Soc. Jpn. 73, 1313 (2004).
- 8) Y. Maeno, T. Ando, Y. Mori, E. Ohmichi, S. Ikeda, S. Nishizaki and S. Nakatsuji: Phys. Rev. Lett. 81 (1998) 3765.
- 9) R. Fittipaldi, A. Vecchione, S. Fusanobori, H. Yaguchi, J. Hooper, R. S. Perry and Y. Maeno: J. Crystal Growth 282 (2005) 152-159.
- 10) Z. Q. Mao, K. D. Nelson, R. Jin, Y. Liu and Y. Maeno: Phys. Rev. Lett 87 (2001) 037003.
- 11) G. E. Blonder, M. Thinkham and T. M. Klapwijk, Phys. Rev. B 25 (1982) 4515.
- 12) I. Iguchi, W. Wang, M. Yamazaki, Y. Tanaka and S. Kashiwara: Phys. Rev. B 62 (2000) R6131.
- 13) Y. Tanaka, Y. Tanuma, K. Kuroki and S. Kashiwara: J. Phys. Soc. Jpn. 71 (2002) 2102.
- 14) The characteristic features in the spectra such as the ZBCP appears mainly for  $I < 0.1$  mA as shown in Fig. 3. Under the assumption of the junction area being  $10 \text{ nm}^2$ ,  $I < 0.1$  mA corresponds to the current density being  $J < 10^3 \text{ A/cm}^2$ . According to our unpublished data, the low temperature critical current density  $J_c$  in pure  $\text{Sr}_2\text{RuO}_4$  is about  $500 \text{ A/cm}^2$ . Besides, the upper critical field for H<sub>k c</sub> in the 3-K phase is about 15 times larger than that in the 1.5-K phase (pure  $\text{Sr}_2\text{RuO}_4$ ). For this reason, the critical current is sufficiently large, so that the features in the spectra reflects properties in the superconducting state.
- 15) H. Yaguchi, K. Takizawa, M. Kawamura, N. Kikugawa, Y. Maeno, T. Mieno, T. Akazaki, K. Semba and H. Takayanagi: in Proc. of 24th Int. Conf. on Low Temperature Physics, eds. Y. Takano, S. P. Hershfeld, S. O. Hill, P. J. Hirschfeld, A. M. Goldman, AIP Conference Proceedings 850, (Springer Verlag, 2006) p. 543. (cond-mat/0609444)